

Reliability Test Result

Product I	GBT	Package	THD
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1. Life Test

Test Item	Test Method/Standard	Test Condition	n [pcs]	Pn [pcs]
High Temperature Reverse Bias	Tjmax、VCE=BVCES Min JEITA ED-4701/100A-101A	1000h	22	0
High Temperature Gate Bias	Ta=Tjmax、VGE=Maximum Rating JEITA ED-4701/100A-101A	1000h	22	0
Temperature humidity bias	Ta=85°C、Rh=85%、VCE=BVCES Min JEITA ED-4701/100A-102A	1000h	22	0
Temperature cycle	Ta= -55°C (30min) ~ Ta=150°C (30min) JEITA ED-4701/100A-105A	200cycle	22	0
Pressure cooker	Ta=121°C、2atm、Rh=100% JESD22-A102C	100h	22	0
High Temperature storage	Ta=Tstgmax JEITA ED-4701/200A-201A	1000h	22	0
Low Temperature storage	Ta=Tstgmin JEITA ED-4701/200A-202A	1000h	22	0

2. Stress Test

Test Item	Test Method/Standard	Test Condition	n [pcs]	Pn [pcs]
Resistance to solder heat1	Dipping into solder bath at 260±5°C. JEITA ED-4701/301-302A	10sec	22	0
Resistance to solder heat2	Dipping leads into solder bath at 350±10°C. JEITA ED-4701/301-302A	3.5sec	22	0
Solderability	Dipping into solder bath at 235±5°C. JEITA ED-4701/301-303A	5sec	22	0
Thermal shock	0^{+5}_{-0} (5min) ~ 100 $^{+0}_{-5}$ (5min) JEITA ED-4701/302-307B	100cycle	22	0
Terminal strength (Pull)	Pull force ; 20N JEITA ED-4701/400A-401A	10sec	22	0
Terminal strength (Bending)	Bending Load ; 10N JEITA ED-4701/400A-401A	2times	22	0

💥 Failure criteria : According to the electrical characteristics specified by the specification.

Regarding solderability test, failure criteria is 95% or more area covered with solder.

※ Sample standard:[Reliability level:90%][Failure reliability level(λ1):10%][C=0 decision] is adopted. And the number of samples is being made 22 in accordance with single sampling inspection plan with exponential distribution type based on MIL-STD-19500.

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3. Test description

Test description		Failure criteria
1.Soldering heat resistance 1 *4	1) Solder Sn-3Ag-0.5Cu(Lead free) 2) <method> Solder temperature 260±5°C Immerse time 10±1s Leaded device: dip the leads once into solder bath the dipping depth should be up to the stopper when the specimen is provided with stopper, and up to 1 to 1.5mm from the body of the specimen when it is not provided with stopper. Surface mount device: dip the whole 3) After dipping, leave at room temperature for more than 2h</method>	Shall be no mechanical damage See * 1 for failure criterion electrical characteristics
2.Soldering heat resistance 2 *4	1) Solder Sn-3Ag-0.5Cu(Lead free) 2) <method> Solder temperature 350±10°C Immerse time 3.5±0.5s Leaded device: dip the leads once into solder bath the dipping depth should be up to the stopper when the specimen is provided with stopper, and up to 1 to 1.5mm from the body of the specimen when it is not provided with stopper. Surface mount device: dip the whole 3) After dipping, leave at room temperature for more than 2h</method>	Shall be no mechanical damage See * 1 for failure criterion electrical characteristics
3. Solderability *4	 Solder Sn-3Ag-0.5Cu(Lead free) Flux 2-propanol(IPA) (Rosin 25wt%) <method> Leader device:Immerse the leads into flux once TIL the point 1.0mm from the package body for 10s, then into solder bath of 245±5°C TIL the point 1.0mm from the package body for 5±0.5s. (mini-mold surface mount device whole body to be immersed). </method> Thereafter, leave for natural dry at room 	•At least 95% of immersed surface must be covered by solder, which is confirmed through 10~20X magnifying glass
4. Heat shock *3	1) <temperature. &time=""> 95~100°C → 0~5°C (Liquid) 5min ← (Liquid) 5min 2) Freq. 100 cycles 3) After completion of test, leave at room temperature for more than 2h</temperature.>	See *1 for failure criteria on electrical characteristics.
5. Temperature cycle *3	 1) <temperature. &time=""> -55°C → 150°C (AIR) 30min ← (AIR) 30min</temperature.> 2) Freq. 200 cycles 3) After completion of test, leave at room temperature for more than 2h 	See *1 for failure criteria on electrical characteristics.
6. Temperature humidity bias *3	1) Ta=85±3°C RH=85 ±15 % 2) Time 1000h 3) VCE=BVCES(min) 4) After completion of test, leave at room temperature for more than 2h	See *1 for failure criteria on electrical characteristics.

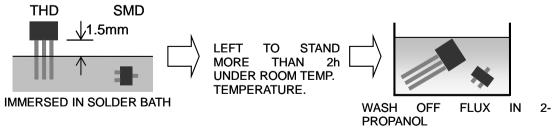
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7. Pressure cooker test *3	1) Ta=121°C、100%RH 2) P=203KPa{2atm} Time 100h 3) After completion of test, leave at room temperature for more than 2h	See *1 for failure criteria on electrical characteristics.
8. High temperature reverse bias *3	 Tj(max)±2°C Time 1000h VCE=BVCES(min) After completion of test, leave at room temperature for more than 2h 	•SAME AS No.1
9. High temperature gate bias [only for FET] *3	 Ta=Tj(max)±2°C Time 1000h VGS=Maximum Rating After completion of test, leave at room temperature for more than 2h 	•SAME AS No.1
10. High temperature storage	 Ta=Tstg(max) Time 1000h After completion of test, leave at room temperature for more than 2h 	•SAME AS No.1
11. Low temperature storage	 Ta=Tstg(min) Time 1000h After completion of test, leave at room temperature for more than 2h 	•SAME AS No.1
12. Lead strength (Lead bend) [only for THD]	Nethod> The sample body is fixed, and the terminal is to be bent by 90° twice, loading specified force to the axis direction.	•Shall be no mechanical damage, detachment, extention between the Lead and the package body
13. Lead strength (Lead pull)	 Method> The sample body is fixed, and keep pulling the lead in lead axis direction with specified load for 10±1s. 	•Shall be no mechanical damage, detachment, extention between the Lead and the package body

4. Remark

*1 Failure criterion : According to the electrical characteristics specified by the specification

*2 Method of No.1,No.2



*3 Preconditioning

[only for SMD]

Soldering Heat resistance (reflow) is carried out after it is Leftunder the high temperature and the high humidity.(85°C,85%,168h) unless specially mentioned

*4 Preconditioning

Aging is done with the PCT device.(105°C,100%,1.22×105Pa,4h)

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